

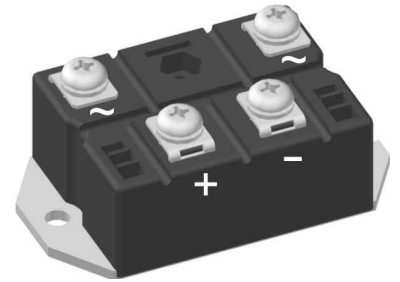
# Standard Rectifier Module

|                           |
|---------------------------|
| <b>1~<br/>Rectifier</b>   |
| $V_{RRM} = 1800\text{ V}$ |
| $I_{DAV} = 160\text{ A}$  |
| $I_{FSM} = 2800\text{ A}$ |

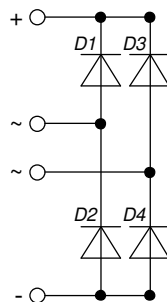
## 1~ Rectifier Bridge

Part number

**VBO160-18NO7**



 E72873



### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

### Applications:

- Diode for main rectification
- For one phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: PWS-E

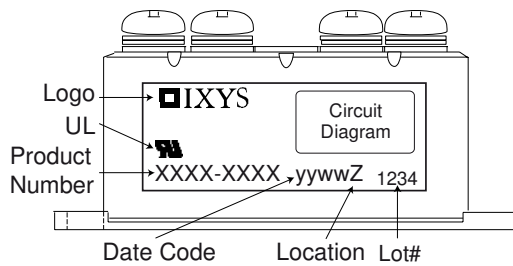
- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Copper internally DCB isolated
- Advanced power cycling

### Disclaimer Notice

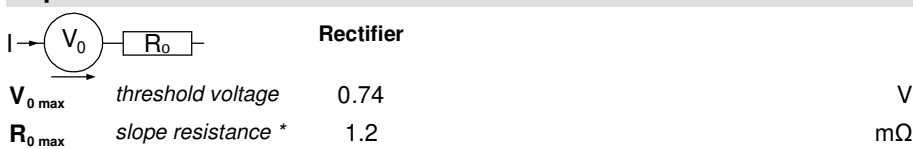
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| Rectifier  |  |                           |         | Ratings                      |      |      |                   |
|------------|--|---------------------------|---------|------------------------------|------|------|-------------------|
| Symbol     | Definition                                   | Conditions                |         | min.                         | typ. | max. | Unit              |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage |                           |         |                              |      | 1900 | V                 |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     |                           |         |                              |      | 1800 | V                 |
| $I_R$      | reverse current                              | $V_R = 1800$ V            |         | $T_{VJ} = 25^\circ\text{C}$  |      | 200  | $\mu\text{A}$     |
|            |  | $V_R = 1800$ V            |         | $T_{VJ} = 150^\circ\text{C}$ |      | 3.5  | mA                |
| $V_F$      | forward voltage drop                         | $I_F = 160$ A             |         | $T_{VJ} = 25^\circ\text{C}$  |      | 1.07 | V                 |
|            |  | $I_F = 320$ A             |         |                              |      | 1.22 | V                 |
|            |  | $I_F = 160$ A             |         | $T_{VJ} = 125^\circ\text{C}$ |      | 0.96 | V                 |
|            |  | $I_F = 320$ A             |         |                              |      | 1.15 | V                 |
| $I_{DAV}$  | bridge output current                        | $T_C = 110^\circ\text{C}$ |         | $T_{VJ} = 150^\circ\text{C}$ |      | 160  | A                 |
|            |  | rectangular               | d = 0.5 |                              |      |      |                   |
| $V_{FO}$   | threshold voltage                            |                           |         | $T_{VJ} = 150^\circ\text{C}$ |      | 0.74 | V                 |
| $r_F$      | slope resistance                             |                           |         |                              |      | 2.4  | m $\Omega$        |
| $R_{thJC}$ | thermal resistance junction to case          |                           |         |                              |      | 0.4  | K/W               |
| $R_{thCH}$ | thermal resistance case to heatsink          |                           |         |                              | 0.15 |      | K/W               |
| $P_{tot}$  | total power dissipation                      |                           |         | $T_C = 25^\circ\text{C}$     |      | 310  | W                 |
| $I_{FSM}$  | max. forward surge current                   | t = 10 ms; (50 Hz), sine  |         | $T_{VJ} = 45^\circ\text{C}$  |      | 2.80 | kA                |
|            |  | t = 8,3 ms; (60 Hz), sine |         | $V_R = 0$ V                  |      | 3.03 | kA                |
|            |  | t = 10 ms; (50 Hz), sine  |         | $T_{VJ} = 150^\circ\text{C}$ |      | 2.38 | kA                |
|            |  | t = 8,3 ms; (60 Hz), sine |         | $V_R = 0$ V                  |      | 2.57 | kA                |
| $I^2t$     | value for fusing                             | t = 10 ms; (50 Hz), sine  |         | $T_{VJ} = 45^\circ\text{C}$  |      | 39.2 | kA <sup>2</sup> s |
|            |  | t = 8,3 ms; (60 Hz), sine |         | $V_R = 0$ V                  |      | 38.1 | kA <sup>2</sup> s |
|            |  | t = 10 ms; (50 Hz), sine  |         | $T_{VJ} = 150^\circ\text{C}$ |      | 28.3 | kA <sup>2</sup> s |
|            |  | t = 8,3 ms; (60 Hz), sine |         | $V_R = 0$ V                  |      | 27.5 | kA <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400$ V; f = 1 MHz  |         | $T_{VJ} = 25^\circ\text{C}$  |      | 133  | pF                |

| Package PWS-E |  |                      | Ratings |      |      |      |
|---------------|--|----------------------|---------|------|------|------|
| Symbol        | Definition   | Conditions           | min.    | typ. | max. | Unit |
| $I_{RMS}$     | RMS current  | per terminal         |         |      | 250  | A    |
| $T_{VJ}$      | virtual junction temperature                                 |                      | -40     |      | 150  | °C   |
| $T_{op}$      | operation temperature  |                      | -40     |      | 125  | °C   |
| $T_{stg}$     | storage temperature  |                      | -40     |      | 125  | °C   |
| <b>Weight</b> |  |                      |         | 273  |      | g    |
| $M_D$         | mounting torque  |                      | 4.25    |      | 5.75 | Nm   |
| $M_T$         | terminal torque  |                      | 4.25    |      | 5.75 | Nm   |
| $d_{Spp/App}$ | creepage distance on surface   striking distance through air | terminal to terminal | 12.0    |      |      | mm   |
| $d_{Spb/Apb}$ |  | terminal to backside | 26.0    |      |      | mm   |
| $V_{ISOL}$    | isolation voltage  | t = 1 second         | 3000    |      |      | V    |
|               |  | t = 1 minute         | 2500    |      |      | V    |



| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | VBO160-18NO7    | VBO160-18NO7       | Box           | 5        | 484024   |

**Equivalent Circuits for Simulation**
*\* on die level*
 $T_{VJ} = 150^{\circ}\text{C}$ 




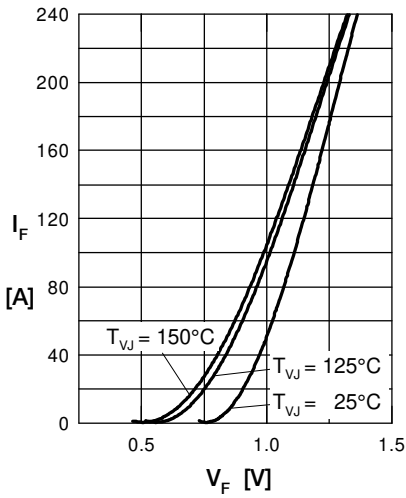
**Rectifier**


Fig. 1 Forward current vs. voltage drop per diode

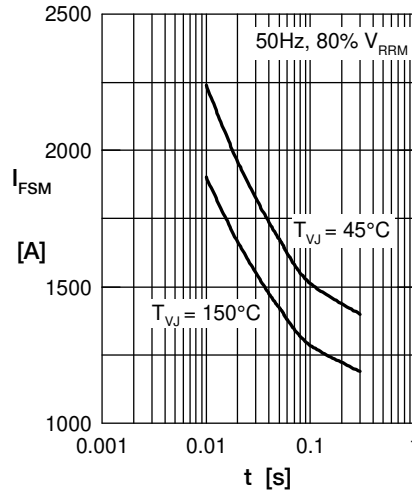


Fig. 2 Surge overload current vs. time per diode

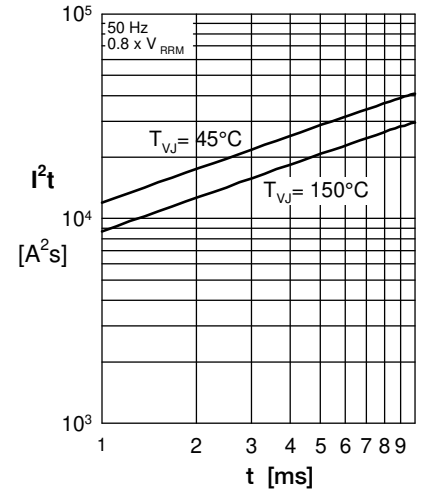
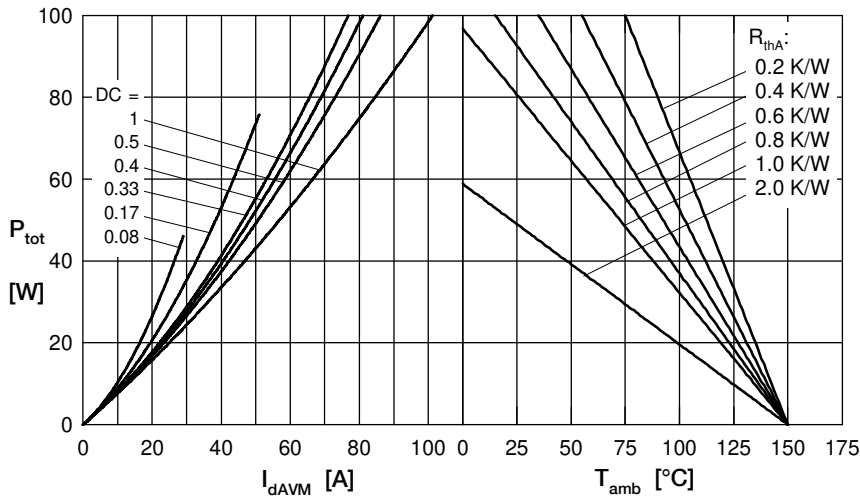

 Fig. 3  $I^2t$  vs. time per diode


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

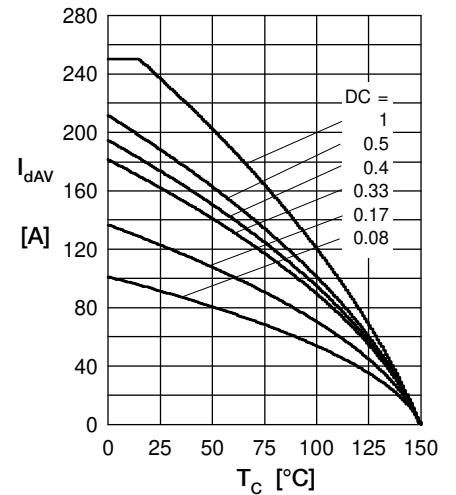


Fig. 5 Max. forward current vs. case temperature per diode

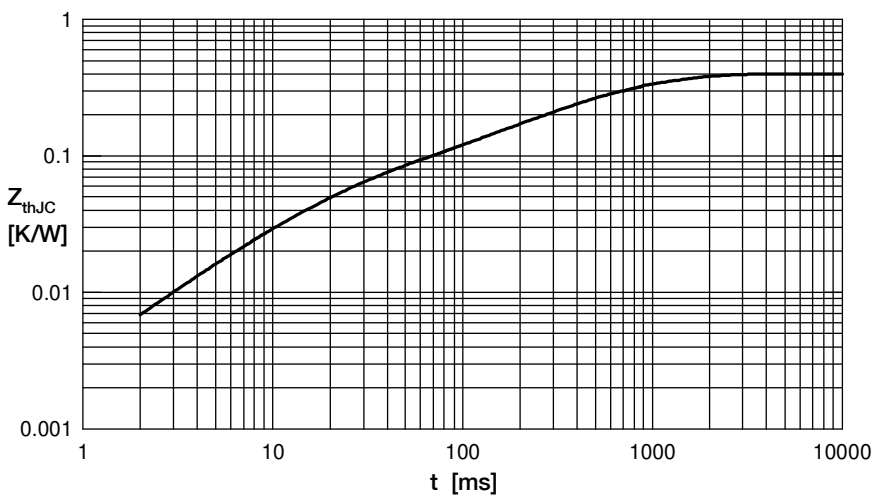


Fig. 6 Transient thermal impedance junction to case vs. time per diode

